

# LM118/LM218/LM318 Operational Amplifiers

## **General Description**

**Connection Diagrams** 

The LM118 series are precision high speed operational amplifiers designed for applications requiring wide bandwidth and high slew rate. They feature a factor of ten increase in speed over general purpose devices without sacrificing DC performance.

The LM118 series has internal unity gain frequency compensation. This considerably simplifies its application since no external components are necessary for operation. However, unlike most internally compensated amplifiers, external frequency compensation may be added for optimum performance. For inverting applications, feedforward compensation will boost the slew rate to over 150V/ $\mu$ s and almost double the bandwidth. Overcompensation can be used with the amplifier for greater stability when maximum bandwidth is not needed. Further, a single capacitor can be added to reduce the 0.1% settling time to under 1  $\mu$ s.

The high speed and fast settling time of these op amps make them useful in A/D converters, oscillators, active fil-

ters, sample and hold circuits, or general purpose amplifiers. These devices are easy to apply and offer an order of magnitude better AC performance than industry standards such as the LM709.

The LM218 is identical to the LM118 except that the LM218 has its performance specified over a  $-25^{\circ}$ C to  $+85^{\circ}$ C temperature range. The LM318 is specified from 0°C to  $+70^{\circ}$ C.

#### Features

- 15 MHz small signal bandwidth
- Guaranteed 50V/µs slew rate
- Maximum bias current of 250 nA
- Operates from supplies of ±5V to ±20V
- Internal frequency compensation
- Input and output overload protected
- Pin compatible with general purpose op amps



### Top View

\*Pin connections shown on schematic diagram and typical applications are for TO-5 package.

Order Number LM118H, LM218H or LM318H See NS Package Number H08C Dual-In-Line Package BAL/COMP - 1 1 8 COMP - 2 INPUT 2 7 V<sup>+</sup> INPUT 3 6 OUTPUT V<sup>-</sup> 4 5 BAL/COMP - 3 TL/H/7766-3

Top View

Order Number LM118J-8, LM318J-8, LM318M or LM318N See NS Package Number J08A, M08A or N08B

# **Absolute Maximum Ratings**

If Military/Aerospace specified devices are required, contact the National Semiconductor Sales Office/ Distributors for availability and specifications. (Note 6)

Supply Voltage	±20V
Power Dissipation (Note 1)	500 mW
Differential Input Current (Note 2)	± 10 mA
Input Voltage (Note 3)	± 15V
Output Short-Circuit Duration	Indefinite

Operating Temperature Range	
LM118	-55°C to +125°C
LM218	-25°C to +85°C
LM318	0°C to + 70°C
Storage Temperature Range	-65°C to +150°C
Lead Temperature (Soldering, 10 sec.)	)
Hermetic Package	300°C
Plastic Package	260°C
Soldering Information	
Dual-In-Line Package	
Soldering (10 sec.)	260°C
Small Outline Package	
Vapor Phase (60 sec.)	215°C
Infrared (15 sec.)	220°C
See AN-450 "Surface Mounting Meth	ods and Their Effect

See AN-450 "Surface Mounting Methods and Their Effect on Product Reliability" for other methods of soldering surface mount devices.

ESD rating to be determined.

Parameter	Conditions	LM118/LM218			LM318			Unite
		Min	Тур	Max	Min	Тур	Max	Units
Input Offset Voltage	$T_A = 25^{\circ}C$		2	4		4	10	mV
Input Offset Current	T <sub>A</sub> = 25°C		6	50		30	200	nA
Input Bias Current	T <sub>A</sub> = 25°C		120	250		150	500	nA
Input Resistance	T <sub>A</sub> = 25°C	1	3		0.5	3		MΩ
Supply Current	$T_A = 25^{\circ}C$		5	8		5	10	mA
Large Signal Voltage Gain	$ \begin{array}{l} T_{A}=25^{\circ}C,  V_{S}=\pm 15V\\ V_{OUT}=\pm 10V,  R_{L}\geq 2 k\Omega \end{array} $	50	200		25	200		V/mV
Siew Rate	$T_A = 25^{\circ}C, V_S = \pm 15V, A_V = 1$ (Note 5)	50	70		50	70		V/µs
Small Signal Bandwidth	$T_A = 25^{\circ}C, V_S = \pm 15V$		15			15		MHz
Input Offset Voltage				6			15	mV
Input Offset Current				100			300	nA
Input Bias Current				500			750	nA
Supply Current	T <sub>A</sub> = 125°C		4.5	7				mA
Large Signal Voltage Gain	$V_{S} = \pm 15V, V_{OUT} = \pm 10V$ $R_{L} \ge 2 k\Omega$	25			20			V/mV
Output Voitage Swing	$V_{\rm S} = \pm 15 V, R_{\rm L} = 2  \mathrm{k} \Omega$	±12	±13		±12	±13		V
Input Voltage Range	$V_{\rm S} = \pm 15 V$	±11.5			±11.5			v
Common-Mode Rejection Ratio		80	100		70	100		dB
Supply Voitage Rejection Ratio		70	80		65	80		dB

Electrical Characteristics (Note 4)

Note 1: The maximum junction temperature of the LM118 is 150°C, the LM218 is 110°C, and the LM318 is 110°C. For operating at elevated temperatures, devices in the TO-5 package must be derated based on a thermal resistance of 150°C/W, junction to ambient, or 45°C/W, junction to case. The thermal resistance of the dual-in-line package is 100°C/W, junction to ambient.

Note 2: The inputs are shunted with back-to-back diodes for overvoltage protection. Therefore, excessive current will flow if a differential input voltage in excess of 1V is applied between the inputs unless some limiting resistance is used.

Note 3: For supply voltages less than ±15V, the absolute maximum input voltage is equal to the supply voltage.

Note 4: These specifications apply for  $\pm 5V \le V_S \le \pm 20V$  and  $-55^{\circ}C \le T_A \le +125^{\circ}C$  (LM118),  $-25^{\circ}C \le T_A \le +85^{\circ}C$  (LM218), and  $0^{\circ}C \le T_A \le +70^{\circ}C$  (LM318). Also, power supplies must be bypassed with 0.1  $\mu$ F disc capacitors.

Note 5: Slew rate is tested with  $V_S = \pm 15V$ . The LM118 is in a unity-gain non-inverting configuration.  $V_{IN}$  is stepped from -7.5V to +7.5V and vice versa. The slew rates between -5.0V and +5.0V and vice versa are tested and guaranteed to exceed  $50V/\mu s$ .

Note 6: Refer to RETS118X for LM118H and LM118J-8 military specifications.

#### Typical Performance Characteristics LM118, LM218 Input Current Voltage Gain **Power Supply Rejection** 115 100 200 TA = 25°C Vs = = 15V 150 BIAS 80 100 SUPPLY REJECTION (dB) OSITIVE SUPPLY 110 NPUT CURRENT (MA) 50 VOLTAGE GAIN (dB) = 25\*0 T. 60 0 10 105 40 NECATIVE SUPPL 125\*0 8 DEESET 20 6 100 ۵ z 0 95 -20 -55 -35 -15 5 25 45 65 85 105 125 5 10 15 20 100 11 10k 100k 1M 100 FREQUENCY (Hz) TEMPERATURE (\*C) SUPPLY VOLTAGE (±V) **Common Mode Rejection Input Noise Voltage** Supply Current 120 3000 5.5 TA = 25 C R<sub>S</sub> = 2 kΩ T<sub>A</sub> = 25°C = ±15V COMMON MODE REJECTION (dB) 1000 100 -55°C SUPPLY CURRENT (mA) 80 50 = 25 300 VOISE (nV/\Hz) 100 100 60 TA = 125°C 30 40 4.5 Rs 100Ω. R 10 20 3 0 4.0 10 100k 100 14 10k 1M 15 20 100 14 101 1001 10M 10 FREQUENCY (Hz) FREQUENCY (Hz) SUPPLY VOLTAGE (±V) **Closed Loop Output** Impedance **Current Limiting** Input Current 103 14 600 V<sub>S</sub> = ± 15V T<sub>A</sub> = 25°C V<sub>S</sub> = ±15V TA = 25°C 12 10<sup>2</sup> 400 ĝ Av = 1000 DUTPUT SWING (±V) 10 CURRENT (nA) IMPEDANCE 101 200 Ta = 25" 8 TA = 125°C 100 0 Av 6 **UTPUT I** INN 10 -200 4 -400 10-2 -600 10-3 10 100 11 10k 100k 1M 0 5 10 15 20 25 -0.8 -0.6 -0.4 -0.2 0 0.2 0.4 0.6 0.8 FREQUENCY (Hz) OUTPUT CURRENT (mA) DIFFERENTIAL INPUT (V) Unity Gain Bandwidth **Voltage Follower Slew Rate Inverter Settling Time** 24 130 15 10 mV 22 120 10 UNITY GAIN BANDWIDTH (MHz) $V_c = \pm 20V$ 20 ±15V OUTPUT VOLTAGE (V) 110 100 5 18 SLEW (V/Jus) 100 16 0 =±15V ٧s 90 TA = 25°C 14 NEGATIVE SLEW -5 R<sub>S</sub> = 5 kΩ v. = + 51 80 100 12 Vs = ±15V R1 = 5 kΩ -10 C<sub>t</sub> = 10 pF 70 Rs = R1 = 10 10 10 m V 5 pF C5 7 = 0.1 µF C, 8 60 -15 -55 -35 -15 5 25 45 65 85 105 125 -55 -35 -15 5 25 45 65 85 105 125 0.03 0.1 0.3 1 3 (دىر) TIME TEMPERATURE (\*C) TEMPERATURE (\*C)

TL/H/7766-4





FREQUENCY (Hz)

5.0

4.5

4.0

5

TA = 25°C

10

TA = 70°C

SUPPLY VOLTAGE (±V)

15

20

TL/H/7766~6

80

60

40

20

0

100 1k 10k 100k 1M 10M

300 NOISE (nVK/HZ)

100

30

10

3

10 100 Re = 100k

- 16

10k

100k

R<sub>s</sub> = 100Ω, R<sub>s</sub>

1k FREQUENCY (Hz)













t

TL/H/7766-21

100K 1%

LM118

200K

Ra

OUTPUT

TL/H/7766-23

for  $1.5K \le R_q \le 200K$ 



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